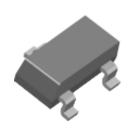
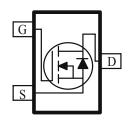
N-Channel 100V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY					
$V_{DS}(V)$	$r_{\mathrm{DS(on)}}(\Omega)$ $I_{\mathrm{D}}($				
100	$0.280 @V_{CS} = 10 V$	1.8			
	$0.355 @V_{CS} = 5.5V$	1.6			

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOT-23 saves board space
- Fast switching speed
- High performance trench technology





ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Maximum	Units	
Drain-Source Voltage			100	V	
Gate-Source Voltage	V_{cs}	±20	V		
Continuous Drain Current ^a	T _A =25°C	I_{D}	1.8	Α	
Pulsed Drain Current ^b	I_{DM}	±10	А		
Continuous Source Current (Diode Conduction) ^a		I_S	1.1	A	
Power Dissipation ^a	T _A =25°C	P_{D}	1.30	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	$^{\circ}\!\mathrm{C}$	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Тур	Max			
M · I · · · · · · · · · · · · · · · · ·	t <= 10 sec	R_{thJA}	93	110	00/W	
Maximum Junction-to-Ambient ^a	Steady State		130	150	°C/W	

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

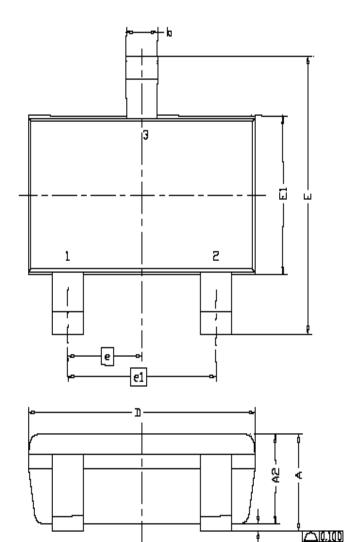
SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
D	G 1.1	T. (C. 11)	Limits			T T •4	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1.0			V	
Gate-Body Leakage	IGSS	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			±100	nA	
Zero Cate Voltage Drain Current	Ides	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
	IDSS	$V_{DS} = 80 \text{ V}, V_{CS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			10	uA	
On-State Drain Current ^A	I _{D(on)}	$V_{DS}=5V$, $V_{GS}=10V$	10			Α	
Drain-Source On-Resistance ^A	IDS(on)	$V_{GS} = 10 \text{ V}, I_D = 1.8 \text{ A}$			280	mΩ	
Drain-Source On-Resistance		$V_{GS} = 5.5 \text{ V}, I_D = 1.6 \text{ A}$			355		
Forward Tranconductance ^A	gs	$V_{DS} = 10 \text{ V}, I_D = 1.8 \text{ A}$		11.3		S	
Diode Forward Voltage	Vsd	$I_S = 1.6 A, V_{GS} = 0 V$		0.75		V	
Dynamic ^b							
Total Gate Charge	Qg			7.0			
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 5.5 \text{ V}, I_D = 1.8 \text{ A}$		1.1		пC	
Gate-Drain Charge	Q_{gd}			2.0			
Turn-On Delay Time	td(on)			8			
Rise Time	tr	$V_{DD}=10 \text{ V}, \text{ RL}=15 \Omega, \text{ ID}=1 \text{ A},$		24			
Tum-Off Delay Time	t _{d(off)}	V _{GEN} =4.5 V		35		ns	
Fall-Time	tf			10			

Notes

- a. Pulse test: $PW \le 300us duty cycle \le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information



DIM.	MILLIMETERS			
ייונת	MIN	NDM	MAX	
Α	0.935	0.95	1.10	
A1	0.01	-	0.10	
A2	0.85	0.90	0.925	
Ф	0.30	0.40	0.50	
u	0.10	0.15	0.25	
D	2.70	2.90	3.10	
П	2.60	2.80	3.00	
E1	1.40	1.60	1.80	
6	0.95 BSC			
el	1.90 BSC			
Г	0.30	0.40	0.60	
L1	0.60REF			
LZ	0,25BSC			
R	0.10			
θ	Ů.	4*	8*	
01	7*NDM			

